



**600V 8A**  
**APT8DQ60K    APT8DQ60SA**  
**APT8DQ60KG\*    APT8DQ60SAG\***

\*G Denotes RoHS Compliant, Pb Free Terminal Finish.

**ULTRAFAST SOFT RECOVERY RECTIFIER DIODE**

**PRODUCT APPLICATIONS**

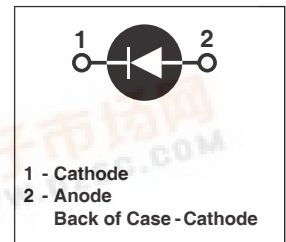
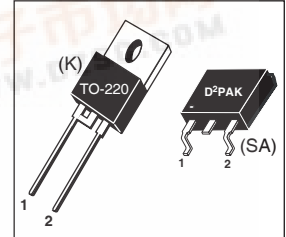
- Anti-Parallel Diode
  - Switchmode Power Supply
  - Inverters
- Free Wheeling Diode
  - Motor Controllers
  - Converters
  - Inverters
- Snubber Diode
- PFC

**PRODUCT FEATURES**

- Ultrafast Recovery Times
- Soft Recovery Characteristics
- Popular TO-220 Package or Surface Mount D<sup>2</sup> PAK Package
- Low Forward Voltage
- Low Leakage Current
- Avalanche Energy Rated

**PRODUCT BENEFITS**

- Low Losses
- Low Noise Switching
- Cooler Operation
- Higher Reliability Systems
- Increased System Power Density



**MAXIMUM RATINGS**

All Ratings:  $T_C = 25^\circ\text{C}$  unless otherwise specified.

Symbol	Characteristic / Test Conditions	APT8DQ60K_SA(G)	UNIT
$V_R$	Maximum D.C. Reverse Voltage	600	Volts
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage		
$V_{RWM}$	Maximum Working Peak Reverse Voltage		
$I_{F(AV)}$	Maximum Average Forward Current ( $T_C = 128^\circ\text{C}$ , Duty Cycle = 0.5)	8	Amps
$I_{F(RMS)}$	RMS Forward Current (Square wave, 50% duty)	16	
$I_{FSM}$	Non-Repetitive Forward Surge Current ( $T_J = 45^\circ\text{C}$ , 8.3ms)	110	
$E_{AVL}$	Avalanche Energy (1A, 40mH)	20	mJ
$T_J, T_{STG}$	Operating and Storage Temperature Range	-55 to 175	$^\circ\text{C}$
$T_L$	Lead Temperature for 10 Sec.	300	

**STATIC ELECTRICAL CHARACTERISTICS**

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT	
$V_F$	Forward Voltage		$I_F = 8\text{A}$	2.0	2.4	Volts
			$I_F = 16\text{A}$	2.5		
			$I_F = 8\text{A}, T_J = 125^\circ\text{C}$	1.5		
$I_{RM}$	Maximum Reverse Leakage Current		$V_R = 600\text{V}$		25	$\mu\text{A}$
			$V_R = 600\text{V}, T_J = 125^\circ\text{C}$		500	
$C_T$	Junction Capacitance, $V_R = 200\text{V}$		16		pF	

**DYNAMIC CHARACTERISTICS**

**APT8DQ60K\_SA(G)**

Symbol	Characteristic	Test Conditions	MIN	TYP	MAX	UNIT
$t_{rr}$	Reverse Recovery Time	$I_F = 1A, di_F/dt = -100A/\mu s, V_R = 30V, T_J = 25^\circ C$	-	14		ns
$t_{rr}$	Reverse Recovery Time		-	19		
$Q_{rr}$	Reverse Recovery Charge	$I_F = 8A, di_F/dt = -200A/\mu s, V_R = 400V, T_C = 25^\circ C$	-	17		nC
$I_{RRM}$	Maximum Reverse Recovery Current		-	2	-	Amps
$t_{rr}$	Reverse Recovery Time	$I_F = 8A, di_F/dt = -200A/\mu s, V_R = 400V, T_C = 125^\circ C$	-	90		ns
$Q_{rr}$	Reverse Recovery Charge		-	160		nC
$I_{RRM}$	Maximum Reverse Recovery Current		-	3	-	Amps
$t_{rr}$	Reverse Recovery Time	$I_F = 8A, di_F/dt = -1000A/\mu s, V_R = 400V, T_C = 125^\circ C$	-	43		ns
$Q_{rr}$	Reverse Recovery Charge		-	250		nC
$I_{RRM}$	Maximum Reverse Recovery Current		-	11		Amps

**THERMAL AND MECHANICAL CHARACTERISTICS**

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-Case Thermal Resistance			2.7	$^\circ C/W$
$W_T$	Package Weight		0.07		oz
			1.9		g
Torque	Maximum Mounting Torque			10	lb•in
				1.1	N•m

APT Reserves the right to change, without notice, the specifications and information contained herein.

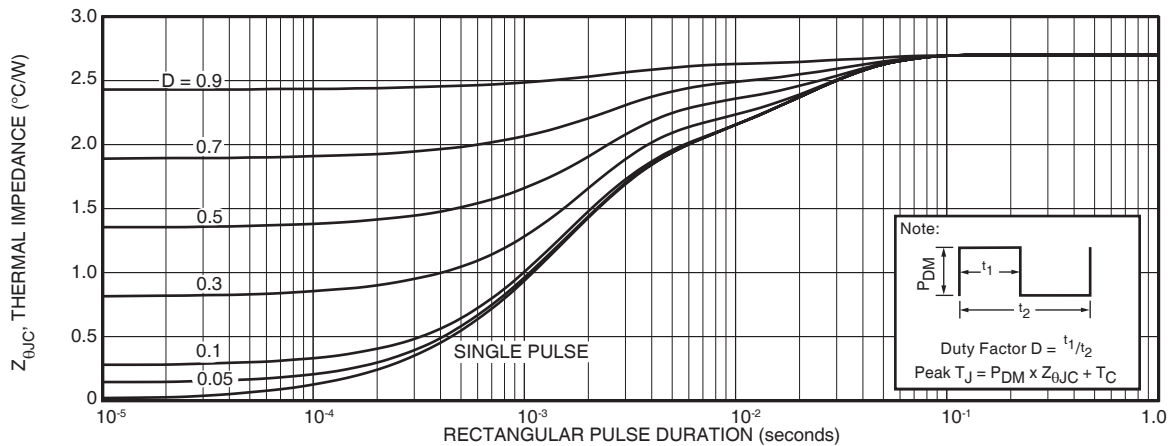


FIGURE 1a. MAXIMUM EFFECTIVE TRANSIENT THERMAL IMPEDANCE, JUNCTION-TO-CASE vs. PULSE DURATION

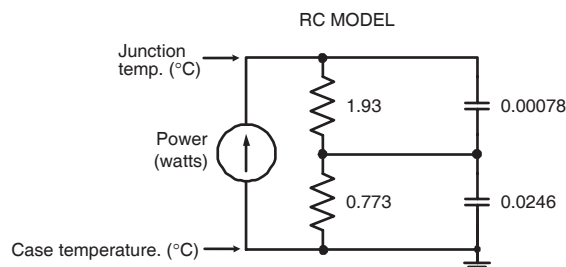
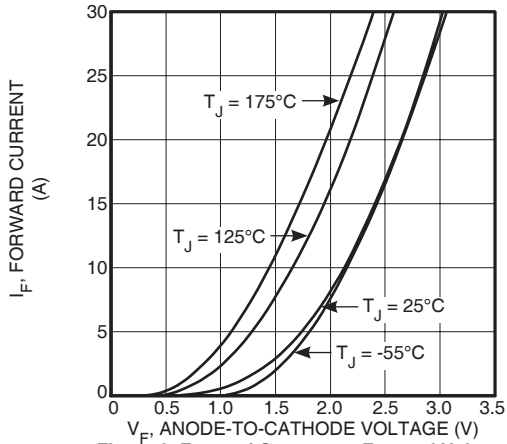


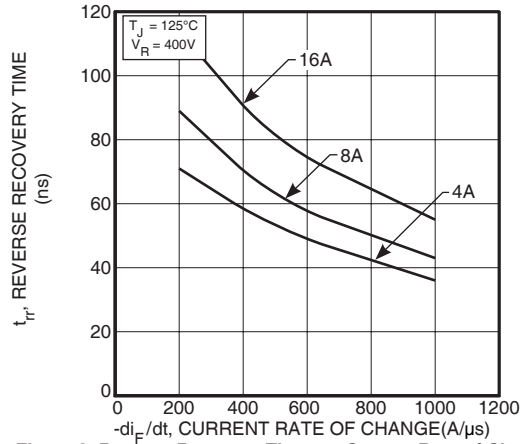
FIGURE 1b. TRANSIENT THERMAL IMPEDANCE MODEL

**TYPICAL PERFORMANCE CURVES**

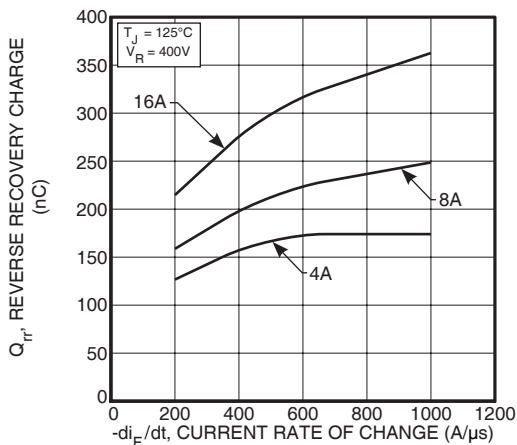
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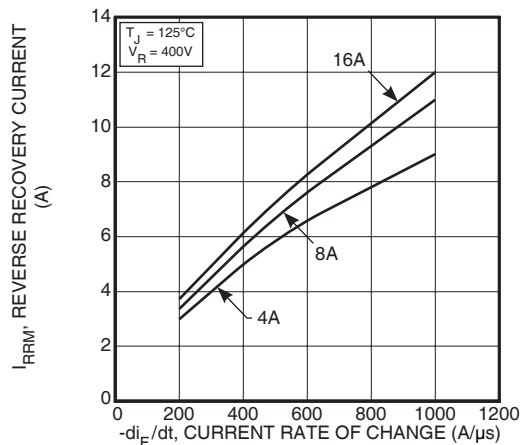
**Figure 2. Forward Current vs. Forward Voltage**



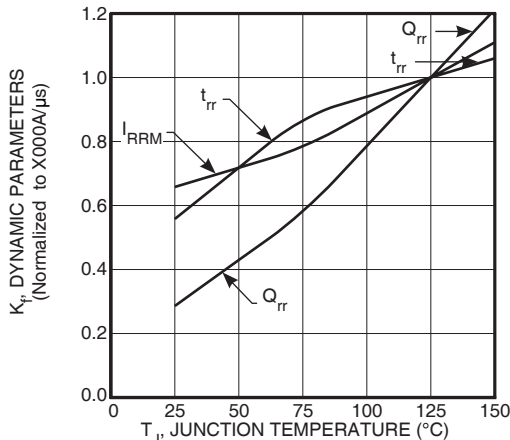
**Figure 3. Reverse Recovery Time vs. Current Rate of Change**



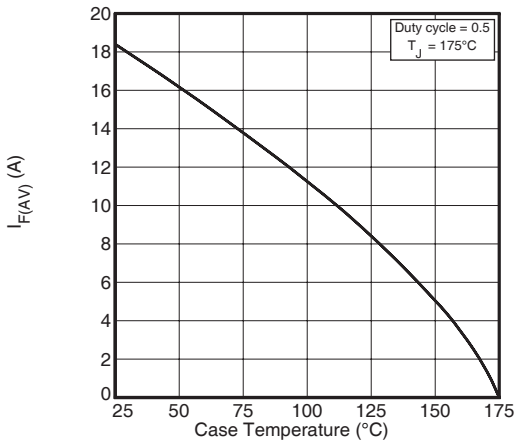
**Figure 4. Reverse Recovery Charge vs. Current Rate of Change**



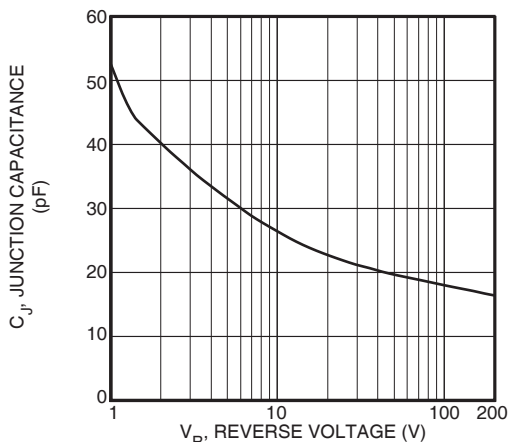
**Figure 5. Reverse Recovery Current vs. Current Rate of Change**



**Figure 6. Dynamic Parameters vs. Junction Temperature**



**Figure 7. Maximum Average Forward Current vs. Case Temperature**



**Figure 8. Junction Capacitance vs. Reverse Voltage**

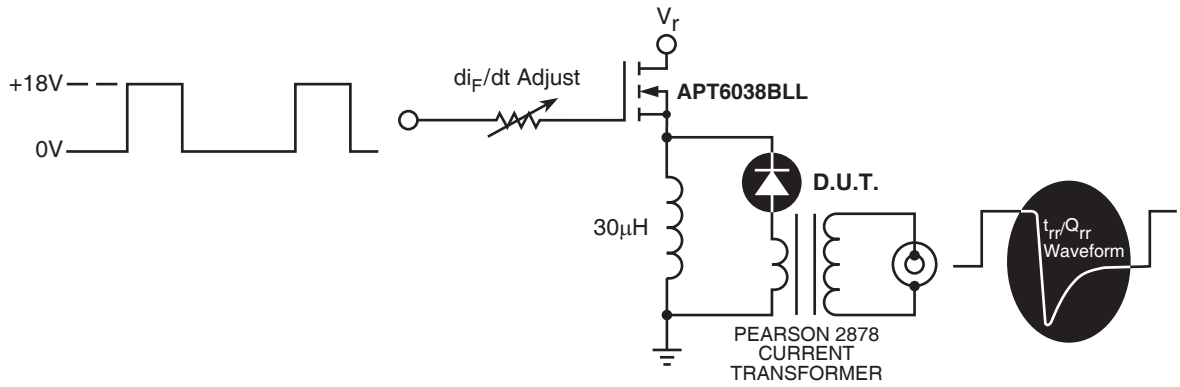


Figure 9. Diode Test Circuit

- 1  $I_F$  - Forward Conduction Current
- 2  $di_F/dt$  - Rate of Diode Current Change Through Zero Crossing.
- 3  $I_{RRM}$  - Maximum Reverse Recovery Current.
- 4  $t_{rr}$  - Reverse Recovery Time, measured from zero crossing where diode current goes from positive to negative, to the point at which the straight line through  $I_{RRM}$  and  $0.25 \cdot I_{RRM}$  passes through zero.
- 5  $Q_{rr}$  - Area Under the Curve Defined by  $I_{RRM}$  and  $t_{rr}$ .

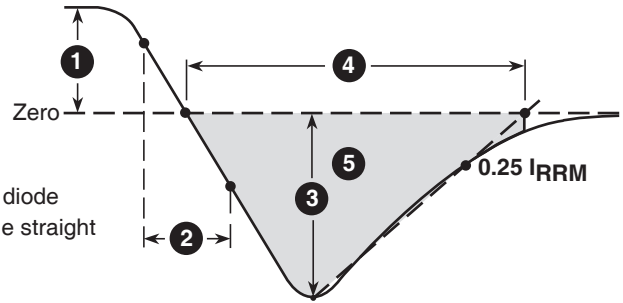
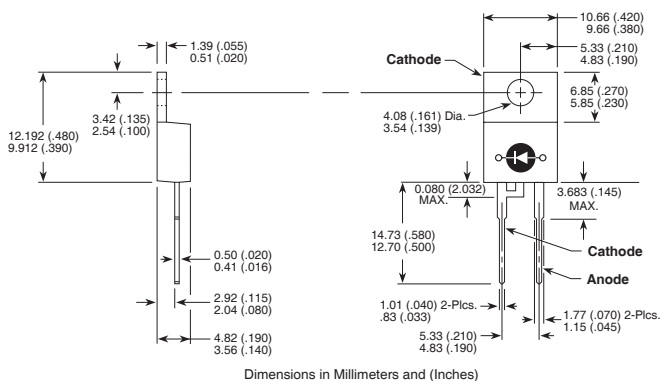


Figure 10, Diode Reverse Recovery Waveform and Definitions

TO-220 (K) Package Outline

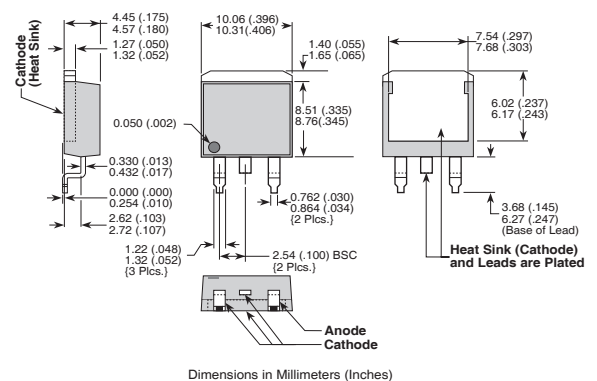
ⓔ3 100% Sn



Dimensions in Millimeters and (Inches)

TO-263 D<sup>2</sup> (SA) Package Outline

ⓔ3 100% Sn



Dimensions in Millimeters (Inches)